

	Type	Hits	Search Text	DBs
1	BRS	757	361/93.1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	BRS	4442	current adj (sense sensing) adj resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
3	BRS	178	current adj (sense sensing) near (MOS MOSFET FET field adj effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
4	BRS	0	current adj (sense sensing) near (MOS MOSFET FET field adj effect) near switch	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
5	BRS	36	current adj (sense sensing) near (MOS MOSFET FET field adj effect) same switch	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
6	BRS	4	5,986,441	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
7	BRS	5	("4914542"   "5004970"   "5008586"   "5164659"   "5220207").PN.	USPAT
8	BRS	10	5,805,434	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
9	BRS	3	6,282,107	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
10	BRS	12	("4975821"   "5126931"   "5331533"   "5374857"   "5434768"   "5734563"   "5774350"   "5805434"   "5812383"   "5814884"   "5886383"   "5973939").PN.	USPAT
11	BRS	12	("4975821"   "5126931"   "5331533"   "5374857"   "5434768"   "5734563"   "5774350"   "5805434"   "5812383"   "5814884"   "5886383"   "5973939").PN.	USPAT
12	BRS	12	("4975821"   "5126931"   "5331533"   "5374857"   "5434768"   "5734563"   "5774350"   "5805434"   "5812383"   "5814884"   "5886383"   "5973939").PN.	USPAT
13	BRS	217964 5	current adj (sense sensing) near across (MOS MOSFET FET field adj effect switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
14	BRS	3	current adj (sense sensing) near across adj (MOS MOSFET FET field adj effect switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

	<b>Time Stamp</b>	<b>Comments</b>	<b>Error Definition</b>	<b>Errors</b>
1	2004/09/01 09:30			0
2	2004/08/31 09:21			0
3	2004/08/31 09:22			0
4	2004/08/31 09:23			0
5	2004/08/31 11:29			0
6	2004/08/31 11:24			0
7	2004/08/31 11:15			0
8	2004/08/31 11:26			0
9	2004/08/31 11:28			0
10	2004/08/31 11:26			0
11	2004/08/31 11:27			0
12	2004/08/31 11:27			0
13	2004/08/31 11:30			0
14	2004/08/31 11:42			0

	Type	Hits	Search Text	DBs
15	BRS	14	over adj current same voltage adj across adj (MOS MOSFET FET field adj effect switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
16	BRS	14	over adj current same voltage near across adj (MOS MOSFET FET field adj effect switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
17	BRS	5	("4479083"   "4502000"   "4502001"   "4949028"   "4967136").PN.	USPAT
18	BRS	22	5528122.URPN.	USPAT
19	BRS	22	5528122.URPN.	USPAT
20	BRS	130	over adj current and voltage near across adj (MOS MOSFET FET field adj effect switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
21	BRS	92	over adj current and voltage near across adj (MOS MOSFET FET field adj effect switch) and temperature	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
22	BRS	11	over adj current and voltage near across adj (MOS MOSFET FET field adj effect switch) same temperature	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
23	BRS	5	over adj current and voltage near across adj (MOS MOSFET FET field adj effect switch) and temperature adj (sense sensing)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
24	BRS	1	over adj current and voltage near across adj (MOS MOSFET FET field adj effect switch) and temperature adj (compensating compensate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
25	BRS	4	("5530335"   "5554919"   "5721480"   "5736832").PN.	USPAT
26	BRS	3	6014030.URPN.	USPAT
27	BRS	3	6014030.URPN.	USPAT
28	BRS	5	over adj current and voltage near (MOS MOSFET FET field adj effect switch) and temperature adj (compensating compensate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
29	BRS	106644	voltage adj across (MOS MOSFET FET field adj effect switch) and temperature adj (compensating compensate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

	<b>Time Stamp</b>	<b>Comments</b>	<b>Error Definition</b>	<b>Errors</b>
15	2004/08/31 12:07			0
16	2004/08/31 12:11			0
17	2004/08/31 12:09			0
18	2004/08/31 12:10			0
19	2004/08/31 12:10			0
20	2004/08/31 12:11			0
21	2004/08/31 12:12			0
22	2004/08/31 12:27			0
23	2004/08/31 12:35			0
24	2004/08/31 13:15			0
25	2004/08/31 12:54			0
26	2004/08/31 12:56			0
27	2004/08/31 12:56			0
28	2004/08/31 13:34			0
29	2004/08/31 13:34			0

	Type	Hits	Search Text	DBs
30	BRS	14	voltage adj across adj (MOS MOSFET FET field adj effect switch) and temperature adj (compensating compensate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
31	BRS	0	voltage adj across adj (MOS MOSFET FET field adj effect switch) same temperature adj (compensating compensate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
32	BRS	502	temperature adj (compensate compensating) adj resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
33	BRS	0	temperature adj (compensate compensating) adj resistor same operational adj amplifier same voltage adj drop near (MOS FET MOSFET field adj effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
34	BRS	0	temperature adj (compensate compensating) adj resistor same voltage adj drop near (MOS FET MOSFET field adj effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
35	BRS	0	temperature adj (compensate compensating) adj resistor and voltage adj drop near (MOS FET MOSFET field adj effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
36	BRS	40	temperature adj (compensate compensating) adj resistor same operational adj amplifier	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
37	BRS	17	temperature adj (compensate compensating) adj resistor same current adj source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
38	BRS	20	temperature adj (compensate compensating) near resistor same current adj source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
39	BRS	354	324/705	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
40	BRS	6	6,014,030	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
41	BRS	929	324/713	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

	<b>Time Stamp</b>	<b>Comments</b>	<b>Error Definition</b>	<b>Errors</b>
30	2004/08/31 13:37			0
31	2004/08/31 13:38			0
32	2004/08/31 13:39			0
33	2004/08/31 13:40			0
34	2004/08/31 13:40			0
35	2004/08/31 13:41			0
36	2004/08/31 15:57			0
37	2004/08/31 16:03			0
38	2004/08/31 16:25			0
39	2004/08/31 16:25			0
40	2004/09/01 10:25			0
41	2004/09/01 10:32			0